

RoHS

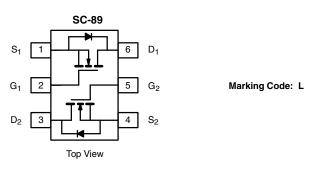
COMPLIANT HALOGEN

FREE

Vishay Siliconix

N-Channel 20 V (D-S) MOSFET

| PRODUCT SI | JMMARY | |
|---------------------|--------------------------------|---------------------|
| V _{DS} (V) | R_{DS(on)} (Ω) | I _D (mA) |
| 20 | 5 at V _{GS} = 4.5 V | 200 |
| | 7 at V _{GS} = 2.5 V | 175 |
| | 9 at V _{GS} = 1.8 V | 150 |
| | 10 at V _{GS} = 1.5 V | 50 |



Ordering Information: Si1034X-T1-GE3 (Lead (Pb)-free and Halogen-free)

FEATURES

- Halogen-free According to IEC 61249-2-21
 Definition
- TrenchFET[®] Power MOSFET: 1.5 V Rated
- Low-Side Switching
- Low On-Resistance: 5 Ω
- Low Threshold: 0.9 V (typ.)
- Fast Switching Speed: 35 ns (typ.)
- 1.5 V Operation
- Gate-Source ESD Protected: 2000 V
- Compliant to RoHS Directive 2002/95/EC

BENEFITS

- Ease in Driving Switches
- Low Offset (Error) Voltage
- Low-Voltage Operation
- High-Speed Circuits
- Low Battery Voltage Operation

APPLICATIONS

- Drivers: Relays, Solenoids, Lamps, Hammers, Displays, Memories
- Battery Operated Systems
- Power Supply Converter Circuits
- Load/Power Switching Cell Phones, Pagers

| ABSOLUTE MAXIMUM RATINGS | $(T_A = 25 \ ^{\circ}C, unle$ | ss otherwise r | noted) | | | |
|---|-------------------------------|-----------------------------------|-------------|--------------|------|--|
| Parameter | | Symbol | 5 s | Steady State | Unit | |
| Drain-Source Voltage | | V _{DS} | 20 | | V | |
| Gate-Source Voltage | | V _{GS} | ± 5 | | v | |
| | T _A = 25 °C | I _D 190 140 | 180 | | | |
| Continuous Drain Current (T _J = 150 °C) ^a | T _A = 85 °C | | 140 | 130 | | |
| Pulsed Drain Current ^b | | I _{DM} | 650 | | mA | |
| Continuous Source Current (Diode Conduction) | | ۱ _S | 450 | 380 | | |
| | T _A = 25 °C | P _D | 280 | 250 | mW | |
| Maximum Power Dissipation ^a | T _A = 85 °C | | 145 | 130 | | |
| Operating Junction and Storage Temperature Range | | T _J , T _{stg} | - 55 to 150 | | °C | |
| Gate-Source ESD Rating (HBM, Method 3015) | | ESD | 2000 | | V | |

Notes:

a. Surface mounted on FR4 board.

b. Pulse width limited by maximum junction temperature.

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| SPECIFICATIONS (T _A = | 25 °C, unl | ess otherwise noted) | | | | |
|---------------------------------------|---------------------|--|------|-------|-------|------|
| Parameter | Symbol | Test Conditions | Min. | Тур. | Max. | Unit |
| Static | | | | | | |
| Gate Threshold Voltage | V _{GS(th)} | $V_{DS} = V_{GS}$, $I_D = 250 \ \mu A$ | 0.40 | | 1.2 | V |
| Gate-Body Leakage | lasa | $V_{DS} = 0 V, V_{GS} = \pm 2.8 V$ | | ± 0.5 | ± 1.0 | |
| Gale-Douy Leakage | I _{GSS} | $V_{DS} = 0 V, V_{GS} = \pm 4.5 V$ | | ± 1.0 | ± 3.0 | μA |
| Zero Gate Voltage Drain Current | Inco | $V_{DS} = 16 V, V_{GS} = 0 V$ | | 1 | 500 | nA |
| Zero Gale Voltage Drain Current | IDSS | V_{DS} = 16 V, V_{GS} = 0 V, T_{J} = 85 °C | | | 10 | μA |
| On-State Drain Current ^a | I _{D(on)} | $V_{DS} = 5 V, V_{GS} = 4.5 V$ | 250 | | | mA |
| Drain-Source On-State | | $V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 200 \text{ mA}$ | | | 5 | Ω |
| | D | V _{GS} = 2.5 V, I _D = 175 mA | | | 7 | |
| Resistance ^a | R _{DS(on)} | V _{GS} = 1.8 V, I _D = 150 mA | | | 9 | |
| | | V _{DS} = 1.5 V, I _D = 40 mA | | | 10 | |
| Forward Transconductance ^a | 9 _{fs} | V _{DS} = 10 V, I _D = 200 mA | | 0.5 | | S |
| Diode Forward Voltage ^a | V _{SD} | I _S = 150 mA, V _{GS} = 0 V | | | 1.2 | V |
| Dynamic ^b | | | | | | |
| Total Gate Charge | Qg | | | 750 | | |
| Gate-Source Charge | Q _{gs} | V_{DS} = 10 V, V_{GS} = 4.5 V, I_D = 150 mA | | 75 | | pC |
| Gate-Drain Charge | Q _{gd} | | | 225 | | |
| Turn-On Delay Time | t _{d(on)} | | | | 50 | |
| Rise Time | t _r | V_{DD} = 10 V, R_L = 47 Ω | | | 25 | |
| Turn-Off Delay Time | t _{d(off)} | $\rm I_D \cong 200~mA,~V_{GEN}$ = 4.5 V, $\rm R_g$ = 10 Ω | | | 50 | ns |
| Fall Time | t _f | | | | 25 | |

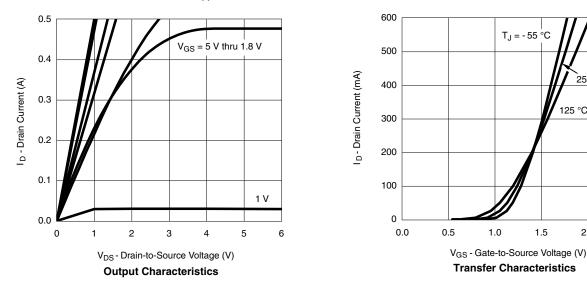
Notes:

a. Pulse test; pulse width \leq 300 $\mu s,$ duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



2.0

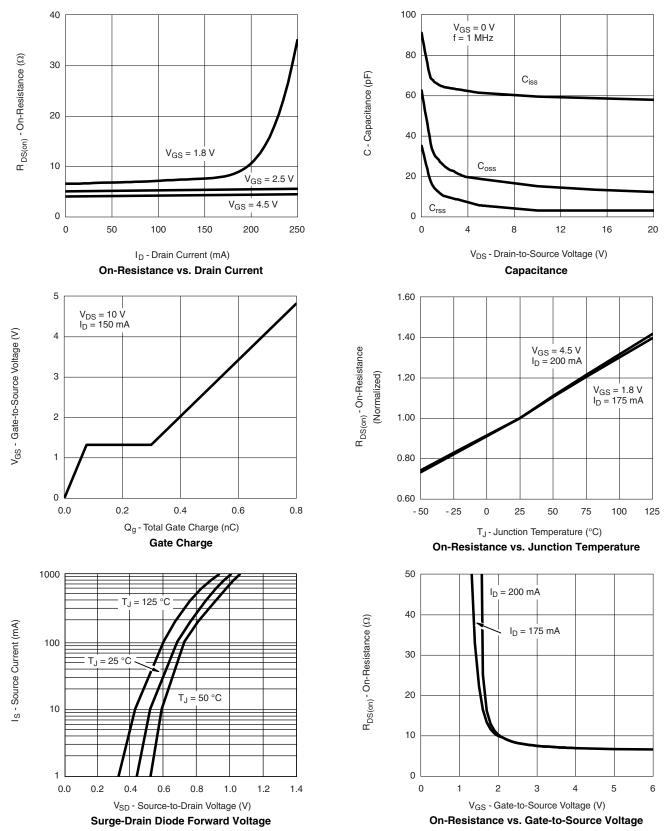
2.5

25 °C

125 °C

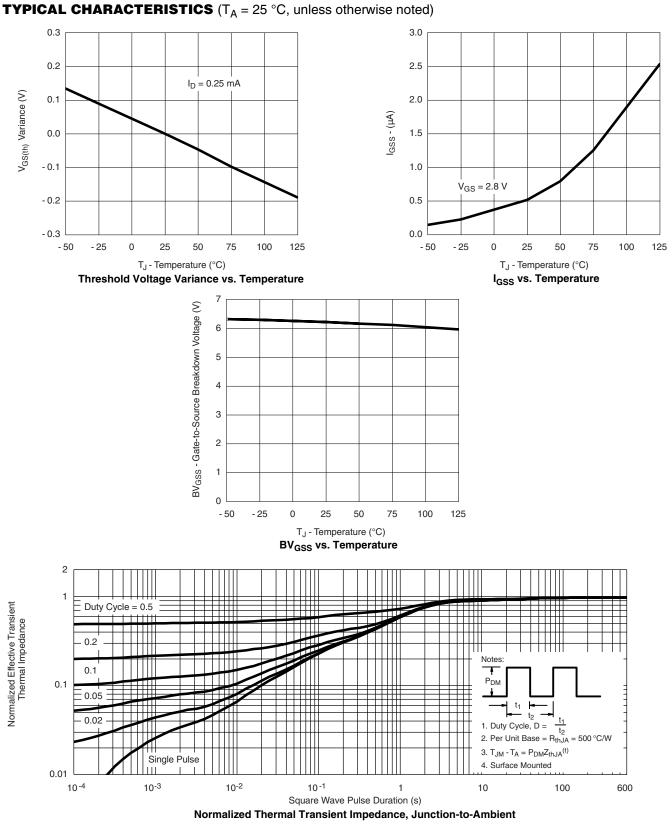


TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



Si1034X

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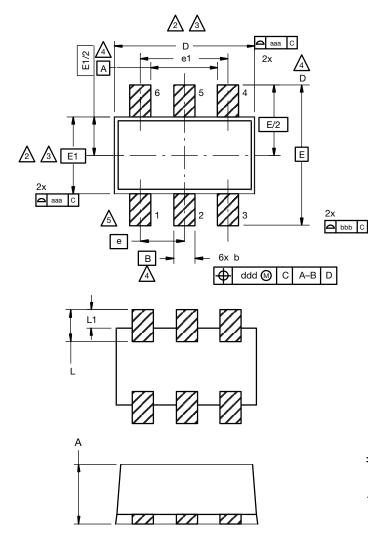
Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?71427.

ISHA



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SC-89 6-Leads (SOT-563F)



Notes

- 1. Dimensions in millimeters.
- Dimension D does not include mold flash, protrusions or gate burrs. Mold flush, protrusions or gate burrs shall not exceed 0.15 mm per dimension E1 does not include interlead flash or protrusion, interlead flash or protrusion shall not exceed 0.15 mm per side.
- A Dimensions D and E1 are determined at the outmost extremes of the plastic body exclusive of mold flash, the bar burrs, gate burrs and interlead flash, but including any mismatch between the top and the bottom of the plastic body.

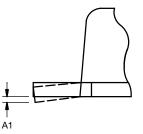
 \underline{A} Datums A, B and D to be determined 0.10 mm from the lead tip.

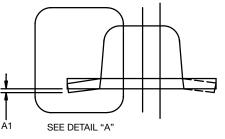
A Terminal numbers are shown for reference only.

A These dimensions apply to the flat section of the lead between 0.08 mm and 0.15 mm from the lead tip.









| DIM. | MILLIMETERS | | | |
|---------------------------|-----------------|------|------|--|
| | MIN. | NOM. | MAX. | |
| А | 0.56 | 0.58 | 0.60 | |
| A1 | 0 | 0.02 | 0.10 | |
| b | 0.15 | 0.22 | 0.30 | |
| С | 0.10 | 0.14 | 0.18 | |
| D | 1.50 | 1.60 | 1.70 | |
| E | 1.50 | 1.60 | 1.70 | |
| E1 | 1.15 | 1.20 | 1.25 | |
| е | 0.45 | 0.50 | 0.55 | |
| e1 | 0.95 | 1.00 | 1.05 | |
| L | 0.25 | 0.35 | 0.50 | |
| L1 | 0.10 | 0.20 | 0.30 | |
| C14-0439-Rev DWG: 5880 | /. C, 11-Aug-14 | | | |

Revision: 11-Aug-14

1 For technical questions, contact: analogswitchtechsupport@vishay.com Document Number: 71612

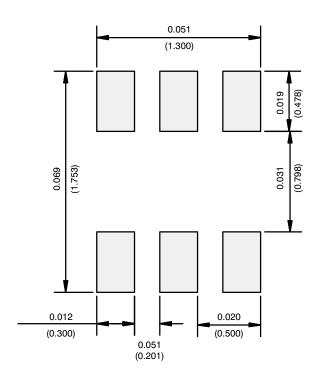
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Application Note 826

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RECOMMENDED MINIMUM PADS FOR SC-89: 6-Lead



Recommended Minimum Pads Dimensions in Inches/(mm)

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